

	Type	L #	Hits	Search Text	DBs	Time Stamp	Comments	Error Definition	Errors
1	BRS	L1	15267	resistor same (insulat\$3 or dielectric or "silicon oxide") same (barrier or metal or conduct\$3 or Al or TiW)	USPAT; EPO; JPO; DERWEN T; IBM TDB	2001/12/17 08:39			0
2	BRS	L7	116187	438/\$.ccls.	USPAT; EPO; JPO; DERWEN T; IBM TDB	2001/12/17 08:01			0
3	BRS	L13	735	1 and 7	USPAT; EPO; JPO; DERWEN T; IBM TDB	2001/12/17 08:02			0
4	BRS	L19	1	"5675310".PN.	USPAT	2001/12/17 08:06			0
5	BRS	L20	1	"5675310".PN.	USPAT	2001/12/17 08:06			0
6	BRS	L21	821	resistor same (insulat\$3 or dielectric or "silicon oxide") same (barrier or metal or conduct\$3 or Al or TiW) same etching	USPAT; EPO; JPO; DERWEN T; IBM TDB	2001/12/17 08:41			0
7	BRS	L27	154	7 and 21	USPAT; EPO; JPO; DERWEN T; IBM TDB	2001/12/17 09:03			0
8	BRS	L33	724	resistor near5 (TiW or barrier)	USPAT; EPO; JPO; DERWEN T; IBM TDB	2001/12/17 09:04			0

	Type	L #	Hits	Search Text	DBs	Time Stamp	n. m en ts	fin iti on
9	BRS	L39	81	33 and 7	USPAT; EPO; JPO; DERWEN T; IBM TDB	2001/12/17 09:04		0